

Switching (200V, 15A)

RDN150N20

●Features

- 1) Low on-resistance.
- 2) Low input capacitance.
- 3) Excellent resistance to damage from static electricity.

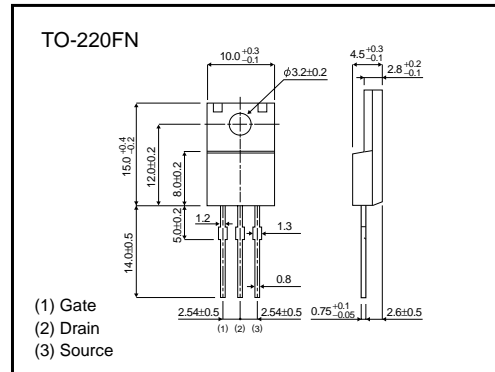
●Application

Switching

●Structure

Silicon N-channel
MOS FET

●External dimensions (Unit : mm)



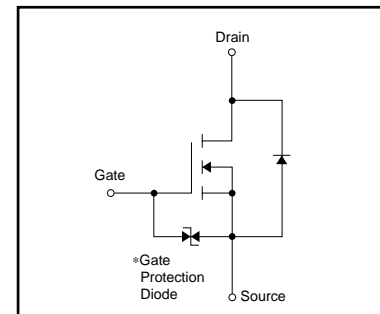
●Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------------------|-------------|--------------|------|
| Drain-Source Voltage | V_{DS} | 200 | V |
| Gate-Source Voltage | V_{GS} | ± 30 | V |
| Drain Current | Continuous | I_D | 15 A |
| | Pulsed | I_{DP} *1 | 45 A |
| Reverse Drain Current | Continuous | I_{DR} | 15 A |
| | Pulsed | I_{DRP} *1 | 45 A |
| Avalanche Current | I_{AS} *2 | 15 | A |
| Avalanche Energy | E_{AS} *2 | 210 | mJ |
| Total Power Dissipation (Tc=25°C) | P_D | 40 | W |
| Channel Temperature | T_{ch} | 150 | °C |
| Storage Temperature | T_{slg} | -55 to +150 | °C |

*1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

*2 $L = 4.5mH$, $V_{DD} = 50V$, $R_G = 25\Omega$, 1Pulse, $T_{ch} = 25^\circ C$

●Equivalent circuit



*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

Transistors

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|---|---------------|------|------|------|------|------------------------------------|
| Gate-Source Leakage | I_{GSS} | — | — | ±10 | μA | $V_{GS}=\pm 30V, V_{DS}=0V$ |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | 200 | — | — | V | $I_D=250\mu A, V_{GS}=0V$ |
| Zero Gate Voltage Drain Current | I_{DSS} | — | — | 25 | μA | $V_{DS}=200V, V_{GS}=0V$ |
| Gate Threshold Voltage | $V_{GS(th)}$ | 2.0 | — | 4.0 | V | $V_{DS}=10V, I_D=1mA$ |
| Static Drain-Source On-State Resistance | $R_{DS(on)}$ | — | 0.12 | 0.16 | Ω | $I_D=7.5A, V_{GS}=10V$ |
| Forward Transfer Admittance | $ Y_{fs} $ | 4.0 | 6.6 | — | S | $V_{DS}=10V, I_D=7.5A$ |
| Input Capacitance | C_{iss} | — | 1224 | — | pF | $V_{DS}=10V$ |
| Output Capacitance | C_{oss} | — | 443 | — | pF | $V_{GS}=0V$ |
| Reverse Transfer Capacitance | C_{rss} | — | 154 | — | pF | $f=1MHz$ |
| Turn-On Delay Time | $t_{d(on)}$ | — | 17 | — | ns | $I_D=7.5A, V_{DD}\approx 100V$ |
| Rise Time | t_r | — | 37 | — | ns | $V_{GS}=10V$ |
| Turn-Off Delay Time | $t_{d(off)}$ | — | 62 | — | ns | $R_L=13\Omega$ |
| Fall Time | t_f | — | 31 | — | ns | $R_G=10\Omega$ |
| Reverse Recovery Time | t_{rr} | — | 158 | — | ns | $I_{DR}=15A, V_{GS}=0V$ |
| Reverse Recovery Charge | Q_{rr} | — | 0.79 | — | μC | $di/dt=100A/\mu s$ |
| Total Gate Charge | Q_g | — | 32 | — | nC | $V_{DD}=100V, V_{GS}=10V, I_D=15A$ |

●Electrical characteristic curves

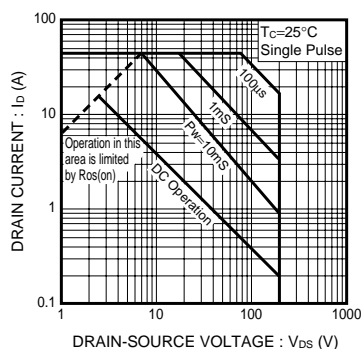


Fig.1 Maximum Safe Operating Area

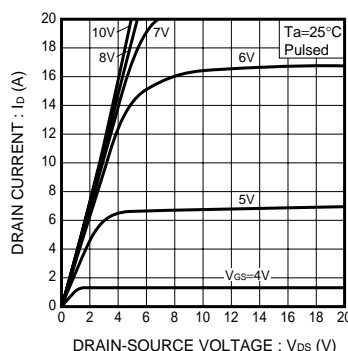


Fig.2 Typical Output Characteristics

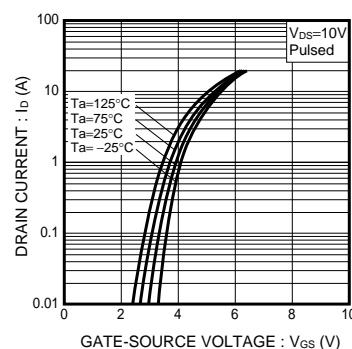


Fig.3 Typical Transfer Characteristics

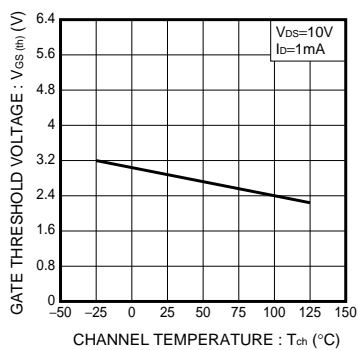


Fig.4 Gate Threshold Voltage vs. Channel Temperature

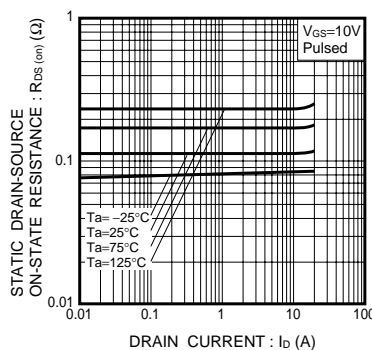


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

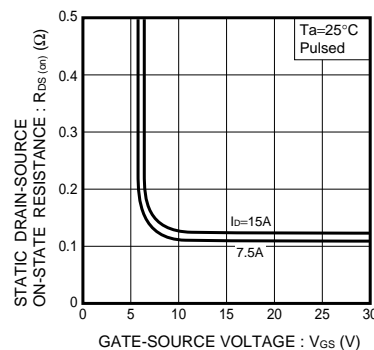


Fig.6 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

Transistors

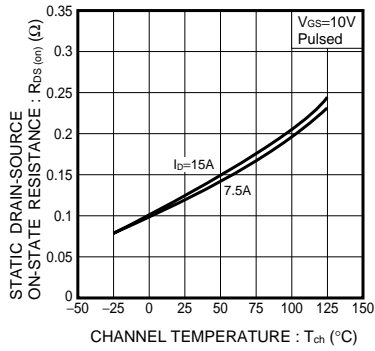


Fig.7 Static Drain-Source On-State Resistance vs. Channel Temperature

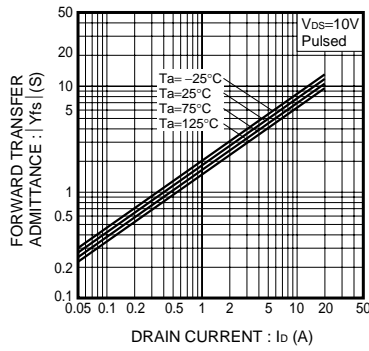


Fig.8 Forward Transfer Admittance vs. Drain Current

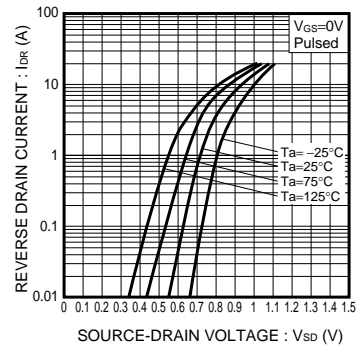


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

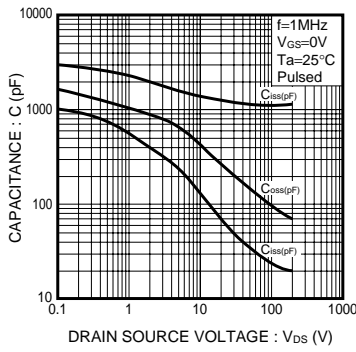


Fig.10 Typical Capacitance vs. Drain-Source Voltage

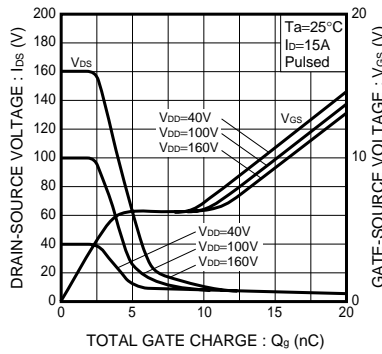


Fig.11 Dynamic Input Characteristics

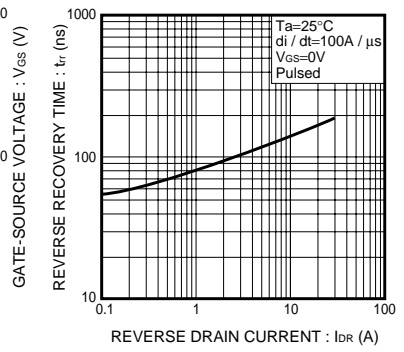


Fig.12 Reverse Recovery Time vs. Reverse Drain Current

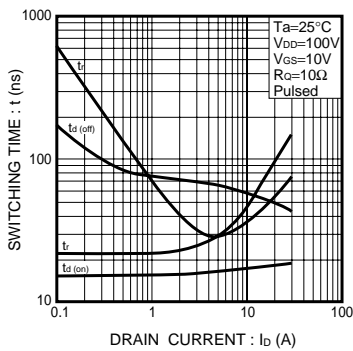


Fig.13 Switching Characteristics

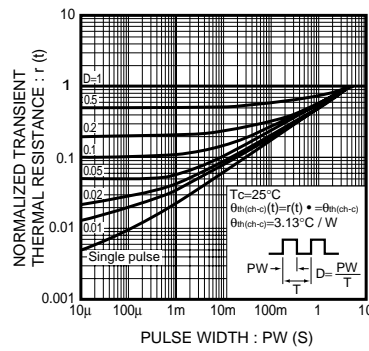


Fig.14 Normalized Transient Thermal Resistance vs. Pulse Width

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